

# **Isc N-Channel MOSFET Transistor**

# IPA80R460CE

#### FEATURES

- With TO-220F package
- · Low input capacitance and gate charge
- Reduced switching and conduction losses
- · 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation



· Switching applications

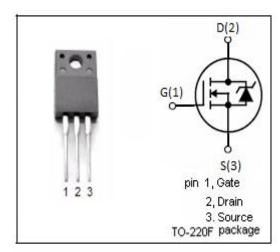


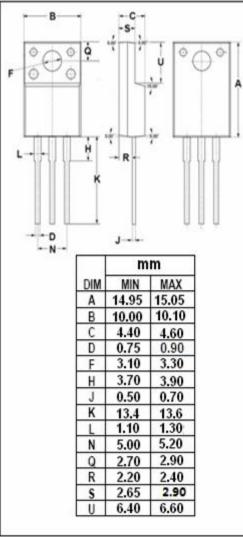
<ul> <li>ABSOLUTE</li> </ul>	MAXIMUM	RATINGS(	T <sub>a</sub> =25℃
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SYMBOL	PARAMETER	VALUE	UNIT	
V <sub>DSS</sub>	Drain-Source Voltage	800	V	
V <sub>GSS</sub>	Gate-Source Voltage	±30	V	
I <sub>D</sub>	Drain Current-Continuous @Tc=25°C (V <sub>GS</sub> at 10V) Tc=100°C	10.8 6.8	А	
I <sub>DM</sub>	Drain Current-Single Pulsed	33	А	
P <sub>D</sub>	Total Dissipation @T <sub>C</sub> =25℃	34	W	
Тј	Max. Operating Junction Temperature	150	$^{\circ}$ C	
T <sub>stg</sub>	Storage Temperature	-55~150	$^{\circ}$ C	

### • THERMAL CHARACTERISTICS

SYMBOL	PARAMETER		UNIT	
Rth(ch-c)	Channel-to-case thermal resistance	3.7	°C/W	
Rth(ch-a)	Channel-to-ambient thermal resistance	80	°C/W	







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#### **ELECTRICAL CHARACTERISTICS**

T<sub>c</sub>=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	MAX	UNIT
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V; I <sub>D</sub> =0.25mA	800			V
$V_{\text{GS(th)}}$	Gate Threshold Voltage	V <sub>DS</sub> = V <sub>GS</sub> ; I <sub>D</sub> =0.68mA	2.1		3.9	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> = 10V; I <sub>D</sub> =7.1A		390	460	mΩ
I <sub>GSS</sub>	Gate-Source Leakage Current	V <sub>GS</sub> =±20V;V <sub>DS</sub> = 0V			±0.1	μА
I <sub>DSS</sub>	Drain-Source Leakage Current	V <sub>DS</sub> = 800V; V <sub>GS</sub> = 0V;Tj=25°C V <sub>DS</sub> = 800V; V <sub>GS</sub> = 0V; Tj=150°C			1 100	μА
V <sub>SDF</sub>	Diode forward voltage	I <sub>SD</sub> =10.8A, V <sub>GS</sub> = 0V		1.0		V

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